

# Built in Biasing Circuit MOS FET IC VHF&UHF RF Amplifier

R07DS0286EJ0800 (Previous: REJ03G0837-0700) Rev.8.00 Mar 28, 2011

## Features

- Built in Biasing Circuit; To reduce using parts cost & PC board space.
- Low noise; NF = 1.0 dB typ. at f = 200 MHz, NF = 1.75 dB typ. at f = 900 MHz
- High gain; PG = 30 dB typ. at f = 200 MHz, PG = 22 dB typ. at f = 900 MHz
- Withstanding to ESD; Built in ESD absorbing diode. Withstand up to 200 V at C = 200 pF, Rs = 0 conditions.
- Provide mini mold packages; MPAK-4 (SOT-143Rmod)

## Outline

RENESAS Package code: PLSP0004ZA-A (Package name: MPAK-4) 1. Source 2. Gate1 3. Gate2 4. Drain Notes: 1. Marking is "DS–". 2. BB504M is individual type number of RENESAS BBFET.

## Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DS</sub>	6	V
Gate1 to source voltage	V <sub>G1S</sub>	+6	V
		-0	
Gate2 to source voltage	V <sub>G2S</sub>	+6	V
		-0	
Drain current	Ι <sub>D</sub>	30	mA
Channel power dissipation	Pch	150	mW
Channel temperature	Tch	150	۵°
Storage temperature	Tstg	-55 to +150	۵°



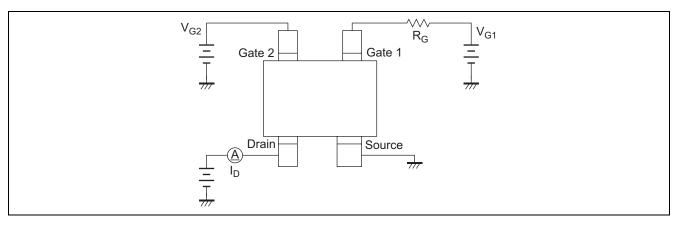
## **Electrical Characteristics**

			-			$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	6		—	V	$I_{D}=200\;\mu A,V_{G1S}=V_{G2S}=0$
Gate1 to source breakdown voltage	$V_{(BR)G1SS}$	+6	—	—	V	$I_{G1} = +10 \ \mu A, \ V_{G2S} = V_{DS} = 0$
Gate2 to source breakdown voltage	V <sub>(BR)G2SS</sub>	+6		_	V	$I_{G2} = +10 \ \mu A, \ V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff current	I <sub>G1SS</sub>	_		+100	nA	$V_{G1S} = +5 V, V_{G2S} = V_{DS} = 0$
Gate2 to source cutoff current	I <sub>G2SS</sub>	—	—	+100	nA	$V_{G2S} = +5 V, V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff voltage	V <sub>G1S(off)</sub>	0.6	0.85	1.1	V	$\label{eq:VDS} \begin{array}{l} V_{\text{DS}} = 5 \ \text{V}, \ V_{\text{G2S}} = 4 \ \text{V} \\ I_{\text{D}} = 100 \ \mu\text{A} \end{array}$
Gate2 to source cutoff voltage	V <sub>G2S(off)</sub>	0.6	0.85	1.1	V	$V_{DS} = 5 V, V_{G1S} = 5 V$ $I_D = 100 \mu A$
Drain current	I <sub>D(op)</sub>	13	16	19	mA	$\label{eq:VDS} \begin{array}{l} V_{DS} = 5 \; V, \; V_{G1} = 5 \; V \\ V_{G2S} = 4 \; V, \; R_G = 120 \; k\Omega \end{array}$
Forward transfer admittance	y <sub>fs</sub>	24	29	34	mS	
Input capacitance	Ciss	1.7	2.1	2.5	pF	$V_{DS} = 5 V, V_{G1} = 5 V$
Output capacitance	Coss	1.0	1.4	1.8	pF	$V_{G2S} = 4 V, R_G = 120 k\Omega$
Reverse transfer capacitance	Crss	_	0.027	0.05	pF	f = 1 MHz
Power gain (1)	PG	25	30		dB	$V_{DS} = 5 V, V_{G1} = 5 V$
Noise figure (1)	NF	—	1.0	1.8	dB	$V_{G2S} = 4 \text{ V}, \text{ R}_{G} = 120 \text{ k}\Omega$ f = 200 MHz
Power gain (2)	PG	17	22	<u> </u>	dB	$V_{DS} = 5 V, V_{G1} = 5 V$
Noise figure (2)	NF	-	1.75	2.3	dB	$V_{G2S} = 4 \text{ V}, \text{ R}_{G} = 120 \text{ k}\Omega$ f = 900 MHz
	< 0	.0		50		

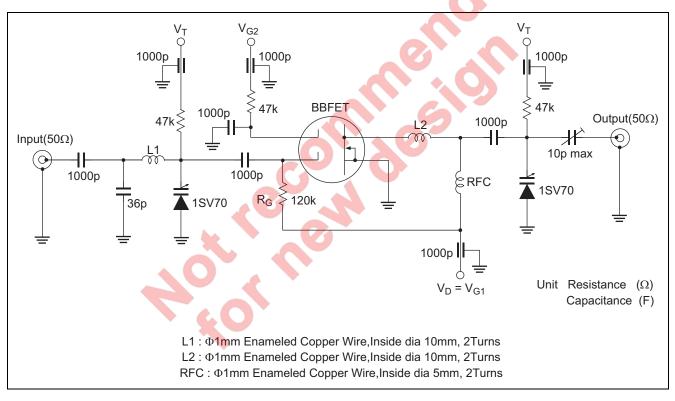


## **Test Circuits**

• DC Biasing Circuit for Operating Characteristics Items (I<sub>D(op)</sub>, |yfs|, Ciss, Coss, Crss, NF, PG)

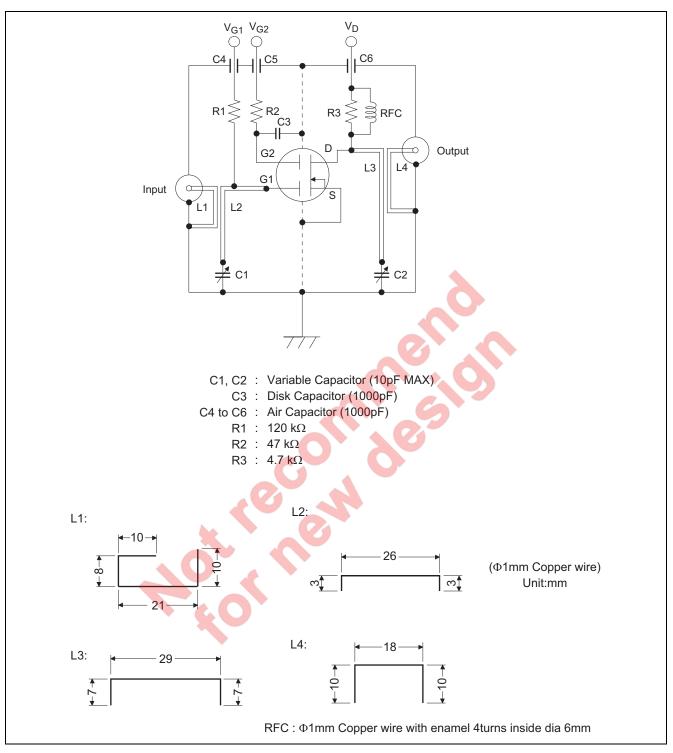


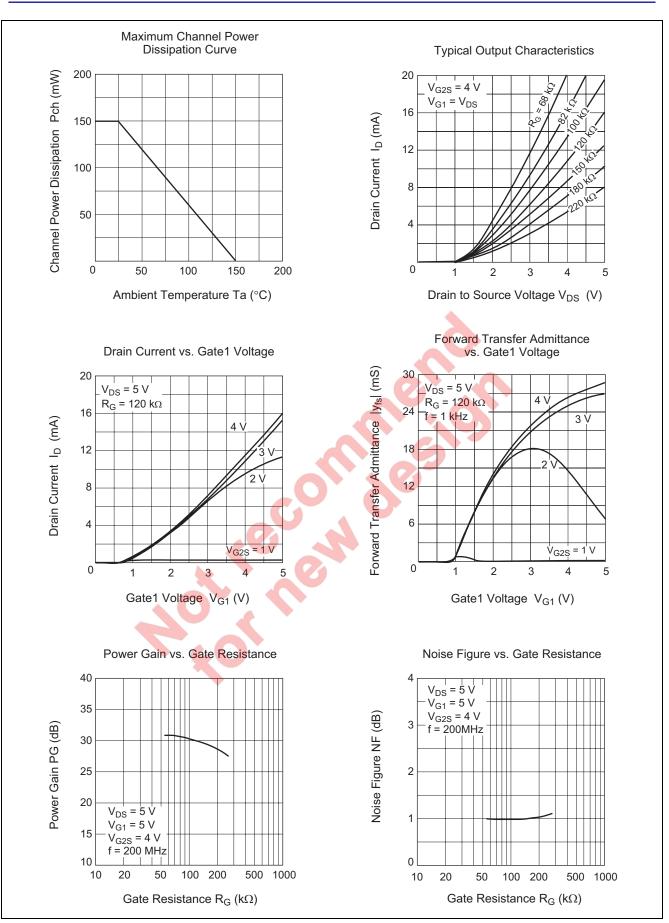
### • 200 MHz Power Gain, Noise Figure Test Circuit



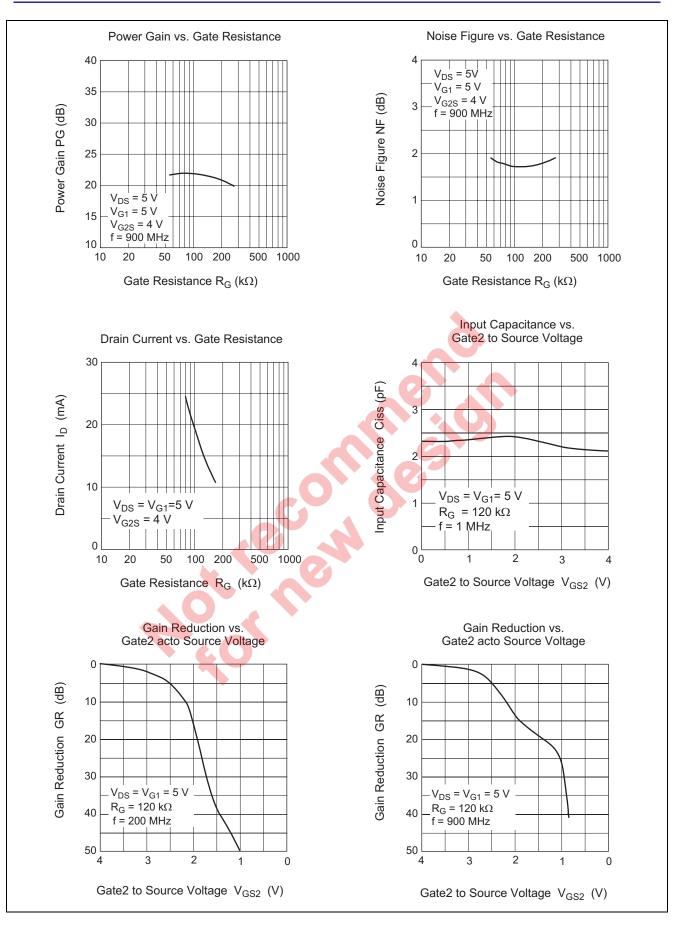


• 900 MHz Power Gain, Noise Figure Test Circuit

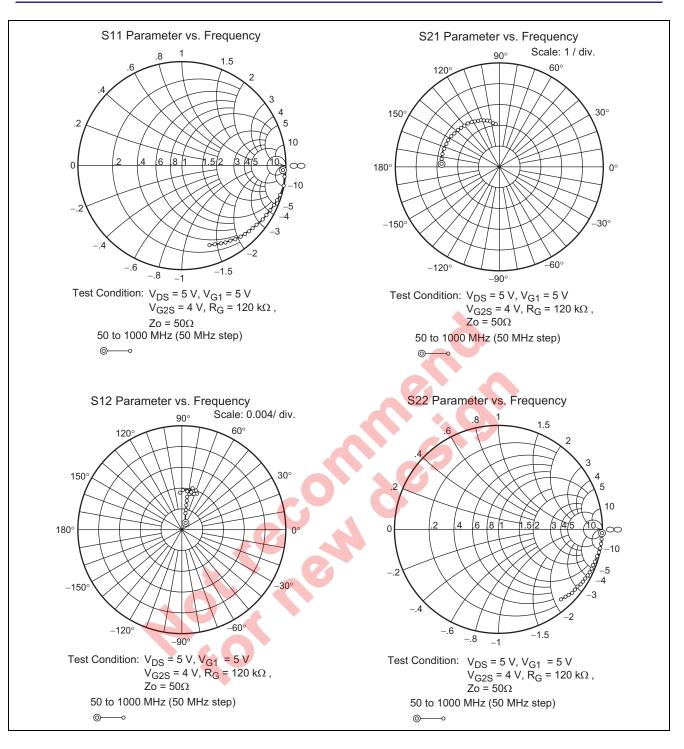












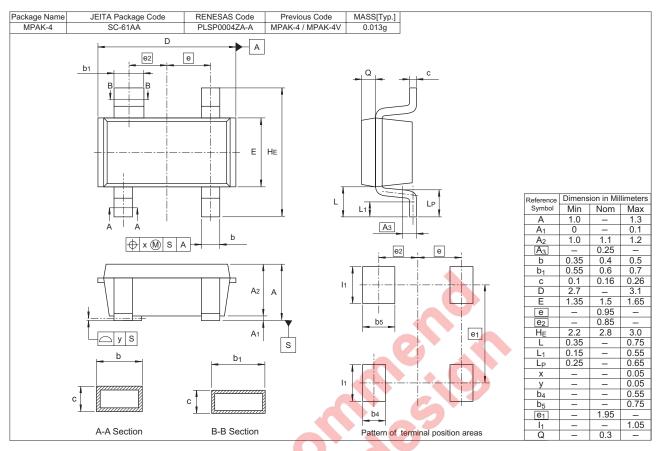


## **S** Parameter

f(MHz)	S11		S21		S	12	S22	
	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
50	1.000	-3.3	2.80	175.9	0.00106	58.8	0.990	-2.4
100	0.993	-7.2	2.78	170.9	0.00171	75.7	0.992	-4.7
150	0.991	-10.9	2.77	166.1	0.00253	75.1	0.991	-7.2
200	0.984	-15.0	2.74	161.2	0.00356	77.4	0.987	-9.6
250	0.978	-19.0	2.72	156.5	0.00442	78.2	0.985	-12.2
300	0.970	-22.8	2.68	151.8	0.00485	80.0	0.982	-14.7
350	0.958	-26.7	2.64	147.2	0.00576	74.7	0.978	-17.1
400	0.954	-30.3	2.60	142.7	0.00642	71.7	0.973	-19.6
450	0.945	-33.8	2.56	138.6	0.00689	73.3	0.968	-22.0
500	0.932	-37.5	2.50	134.1	0.00712	71.8	0.963	-24.2
550	0.920	-40.6	2.46	129.8	0.00765	70.7	0.958	-26.7
600	0.910	-44.3	2.41	125.7	0.00804	69.9	0.952	-28.9
650	0.900	-47.5	2.37	121.6	0.00798	69.1	0.947	-31.3
700	0.887	-50.9	2.31	117.8	0.00787	67.8	0.942	-33.4
750	0.870	-54.4	2.27	113.6	0.00785	70.8	0.936	-35.8
800	0.863	-57.6	2.22	110.0	0.00758	73.3	0.929	-37.9
850	0.853	-60.9	2.18	105.8	0.00721	75.2	0.924	-40.3
900	0.839	-63.6	2.12	102.2	0.00694	75.8	0.917	-42.5
950	0.827	-66.5	2.07	98.6	0.00716	88.1	0.912	-44.5
1000	0.819	-70.1	2.04	94.9	0.00667	92.7	0.906	-46.7



## **Package Dimensions**



## **Ordering Information**

Orderable Part Number	Quantity		Shipping Container
BB504MDS-TL-E	3000	φ 178	8 mm Reel, 8 mm Emboss Taping
BB504MDS-TL-H			

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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